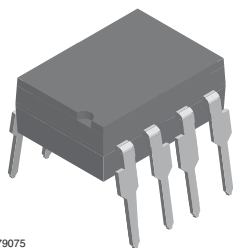
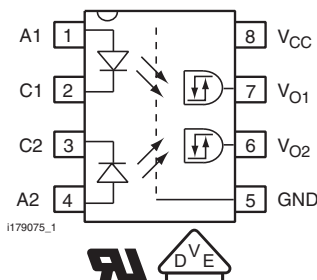


High Speed Optocoupler, Dual, 5 MBd



1179075



FEATURES

- Data rate 5 MBits/s (2.5 MBit/s over temperature)
- Buffer
- Isolation test voltage, 5300 V_{RMS}
- TTL, LSTTL and CMOS compatible
- Internal shield for very high common mode transient immunity
- Wide supply voltage range (4.5 V to 15 V)
- Low input current (1.6 mA to 5 mA)
- Specified from 0 °C to 85 °C
- Compliant to RoHS Directive to 2002/95/EC and in accordance WEEE 2002/96/EC


RoHS
COMPLIANT

DESCRIPTION

The dual channel 5 Mb/s SFH6731 and SFH6732 high speed optocoupler consists of a GaAlAs infrared emitting diode, optically coupled with an integrated photo detector. The detector incorporates a Schmitt-Trigger stage for improved noise immunity. A Faraday shield provides a common mode transient immunity of 1000 V/μs at V_{CM} = 50 V for SFH6731 and 500 V/μs at V_{CM} = 300 V for SFH6732.

The SFH6731 and SFH6732 uses an industry standard DIP-8 package. With standard lead bending, creepage distance and clearance of ≥ 7 mm with lead bending options 6, 7 and 9 ≥ 8 mm are achieved.

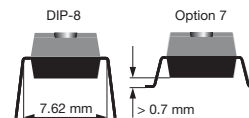
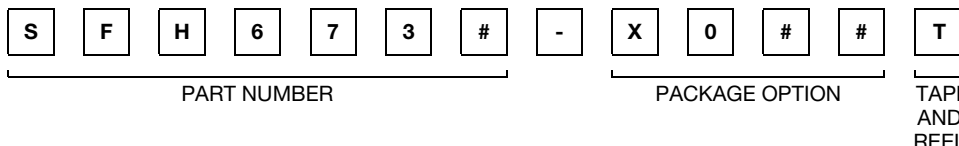
AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending), available with option 1

APPLICATIONS

- Industrial control
- Replace pulse transformers
- Routine logic interfacing
- Motion/power control
- High speed line receiver
- Microprocessor system interfaces
- Computer peripheral interfaces

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CMR (kV/μs)	CMR (kV/μs)
UL	1	5
DIP-8	SFH6731	SFH6732
SMD-8, option 7	-	SFH6732-X007T
VDE, UL	1	5
SMD-8, option 7	SFH6731-X017T	-

TRUTH TABLE (positive logic)

PARTS	IR DIODE	OUTPUT
SFH6731	On	H
	Off	L
SFH6732	On	H
	Off	L



ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	3	V
DC Forward current		I_F	10	mA
Surge forward current	$t_p \leq 1\text{ }\mu\text{s}$, 300 pulses/s	I_{FSM}	1	A
Power dissipation		P_{diss}	20	mW
OUTPUT				
Supply voltage		V_{CC}	- 0.5 to + 15	V
Output voltage		V_O	- 0.5 to + 15	V
Average output current		I_O	25	mA
Power dissipation		P_{diss}	100	mW
COUPLER				
Storage temperature range		T_{stg}	- 55 to + 125	$^{\circ}\text{C}$
Ambient temperature range		T_{amb}	- 40 to + 85	$^{\circ}\text{C}$
Lead soldering temperature	$t = 10\text{ s}$	T_s	260	$^{\circ}\text{C}$
Isolation test voltage	$t = 1\text{ s}$	V_{ISO}	5300	V_{RMS}
Pollution degree			2	
Creepage distance and clearance	Standard lead bending		7	mm
	Option 6, 7, 9		8	mm
Comparative tracking index per DIN IEC 112/VDE 0303, part 1		CTI	175	
Isolation resistance	$V_{IO} = 500\text{ V}$, $T_{amb} = 25\text{ }^{\circ}\text{C}$	R_{IO}	10^{12}	Ω
	$V_{IO} = 500\text{ V}$, $T_{amb} = 100\text{ }^{\circ}\text{C}$	R_{IO}	10^{11}	Ω

Note

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT ⁽¹⁾						
Forward voltage	$I_F = 5\text{ mA}$	V_F		1.6	1.75	V
		V_F			1.8	V
Input current hysteresis	$V_{CC} = 5\text{ V}$, $I_{HYS} = I_{Fon} - I_{Foff}$			01		mA
Reverse current	$V_R = 3\text{ V}$	I_R		0.5	10	μA
Capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$	C_O		60		pF
Thermal resistance		R_{thja}		700		K/W
OUTPUT ⁽¹⁾						
Logic low output voltage	$I_{OL} = 6.4\text{ mA}$	V_{OL}			0.5	V
Logic high output voltage	$I_{OH} = - 2.6\text{ mA}$, $V_{OH} = V_{CC} - 1.8\text{ V}$ ⁽²⁾	V_{OH}	2.4	⁽²⁾		V
Output leakage current ($V_{OUT} > V_{CC}$)	$V_O = 5.5\text{ V}$, $V_{CC} = 4.5\text{ V}$, $I_F = 5\text{ mA}$	I_{OHH}		0.5	100	μA
	$V_O = 15\text{ V}$, $V_{CC} = 4.5\text{ V}$, $I_F = 5\text{ mA}$	I_{OHH}		1	500	μA
Logic low supply current	$V_{CC} = 5.5\text{ V}$, $I_F = 0\text{ A}$	I_{CCL}		3.7	6	mA
	$V_{CC} = 15\text{ V}$, $I_F = 0\text{ A}$	I_{CCL}		4.1	6.5	mA
Logic high supply current	$V_{CC} = 5.5\text{ V}$, $I_F = 5\text{ mA}$	I_{CCH}		3.4	4	mA
	$V_{CC} = 15\text{ V}$, $I_F = 5\text{ mA}$	I_{CCH}		3.7	5	mA
Logic low short circuit output current	$V_O = V_{CC} = 5.5\text{ V}$, $I_F = 0\text{ A}$	I_{OSL}	25			mA
	$V_O = V_{CC} = 15\text{ V}$, $I_F = 0\text{ A}$	I_{OSL}	40			mA



ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
OUTPUT						
Logic high short circuit output current	$V_{CC} = 5.5\text{ V}$, $V_O = 0\text{ V}$, $I_F = 5\text{ mA}$	I_{OSH}			- 10	mA
	$V_{CC} = 15\text{ V}$, $V_O = 0\text{ V}$, $I_F = 5\text{ mA}$	I_{OSH}			- 25	mA
Thermal resistance				300		K/W
COUPLER						
Capacitance (input to output)	$f = 1\text{ MHz}$, pins 1 to 4 and 5 to 8 shorted together	C_{IO}		0.6		pF

Notes

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.
- (1) $0\text{ }^{\circ}\text{C} \leq T_{amb} \leq 85\text{ }^{\circ}\text{C}$; $4.5\text{ V} \leq V_{CC} \leq 15\text{ V}$; $1.6\text{ mA} \leq I_{Fon} \leq 5\text{ mA}$; $2 \leq V_{EH} \leq 15\text{ V}$; $0 \leq V_{EL} \leq 0.8\text{ V}$; $0\text{ mA} \leq I_{Foff} \leq 0.1\text{ mA}$. Typical values: $T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{CC} = 5\text{ V}$; $I_{Fon} = 3\text{ mA}$ unless otherwise specified.
- (2) Output short circuit time $\leq 10\text{ ms}$.

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Propagation delay time to logic low output level	without peaking capacitor	t_{PHL}		120		ns
	with peaking capacitor	t_{PHL}		115	300	ns
	without peaking capacitor	t_{PLH}		125		ns
	with peaking capacitor	t_{PLH}		90	300	ns
Output rise time	10 % to 90 %	t_r		40		ns
Output fall time	90 % to 10 %	t_f		10		ns

Note

- $0\text{ }^{\circ}\text{C} \leq T_{amb} \leq 85\text{ }^{\circ}\text{C}$; $4.5\text{ V} \leq V_{CC} \leq 15\text{ V}$; $1.6\text{ mA} \leq I_{Fon} \leq 5\text{ mA}$; $0\text{ mA} \leq I_{Foff} \leq 0.1\text{ mA}$. Typical values: $T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{CC} = 5\text{ V}$; $I_{Fon} = 3\text{ mA}$ unless otherwise specified.

RECOMMENDED OPERATING CONDITIONS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply voltage		V_{CC}	4.5		15	V
Forward input current		I_{Fon}	1.6 ⁽¹⁾		5	mA
		I_{Foff}			0.1	mA
Operating temperature		T_A	0		85	$^{\circ}\text{C}$

Notes

- A 0.1 μF bypass capacitor connected between pins 5 and 8 must be used.
- (1) We recommend using a 2.2 mA to permit at least 20 % CTR degradation guard band.

COMMON MODE TRANSIENT IMMUNITY							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Logic high common mode transient immunity ⁽¹⁾	$ V_{CM} = 50\text{ V}$, $I_F = 1.6\text{ mA}$	SFH6731	$ CM_H $	1000			V/ μs
	$ V_{CM} = 300\text{ V}$, $I_F = 1.6\text{ mA}$	SFH6732	$ CM_H $	5000			V/ μs
Logic low common mode transient immunity ⁽¹⁾	$ V_{CM} = 50\text{ V}$, $I_F = 0\text{ mA}$	SFH6731	$ CM_L $	1000			V/ μs
	$ V_{CM} = 1000\text{ V}$, $I_F = 0\text{ mA}$	SFH6732	$ CM_L $	10 000			V/ μs

Notes

- $T_{amb} = 25\text{ }^{\circ}\text{C}$, $V_{CC} = 5\text{ V}$ ⁽¹⁾
- (1) CMH is the maximum slew rate of a common mode voltage VCM at which the output voltage remains at logic high level ($V_O > 2\text{ V}$). CML is the maximum slew rate of a common mode voltage VCM at which the output voltage remains at logic low level ($V_O < 0.8\text{ V}$).

SAFETY AND INSULATION RATINGS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC 68 part 1)				55/100/21		
Comparative tracking index		CTI	175		399	
V_{IOTM}			8000			V
V_{IORM}			890			V
P_{SO}					500	mW
I_{SI}					300	mA
T_{SI}					175	°C
Creepage distance	Standard DIP-8		7			mm
Clearance distance	Standard DIP-8		7			mm
Creepage distance	400 mil DIP-8		8			mm
Clearance distance	400 mil DIP-8		8			mm

Note

- As per DIN EN 60747-5-2 (VDE 0884), § 7.4.3.8.1, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

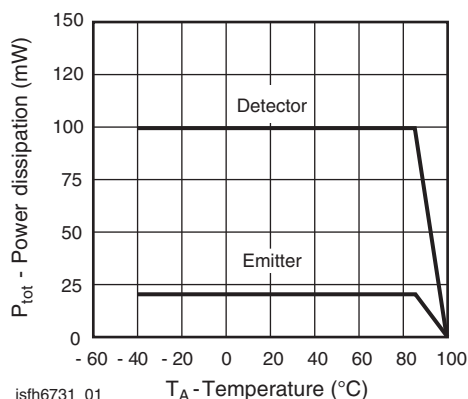
TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ °C}$, unless otherwise specified)


Fig. 1 - Permissible Total Power Dissipation vs. Temperature

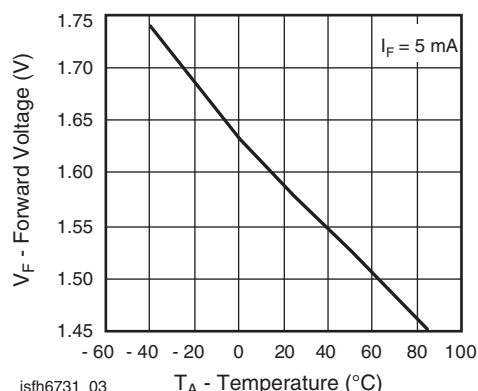


Fig. 3 - Typical Forward Input Voltage vs. Temperature

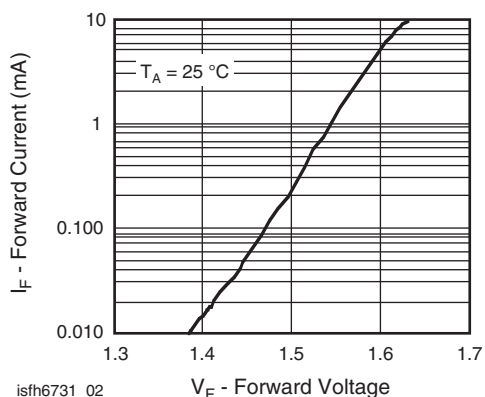


Fig. 2 - Typical Input Diode Forward Current vs. Forward Voltage

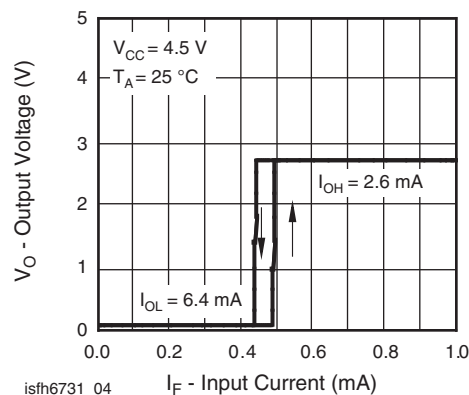


Fig. 4 - Typical Output Voltage vs. Forward Input Current

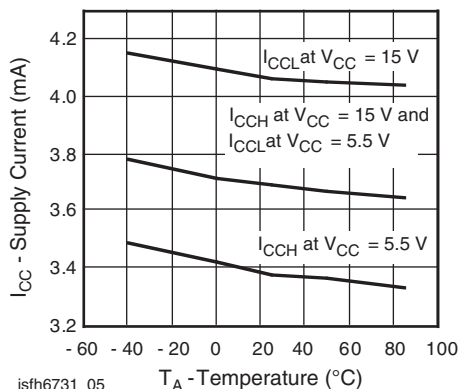


Fig. 5 - Typical Supply Current vs. Temperature

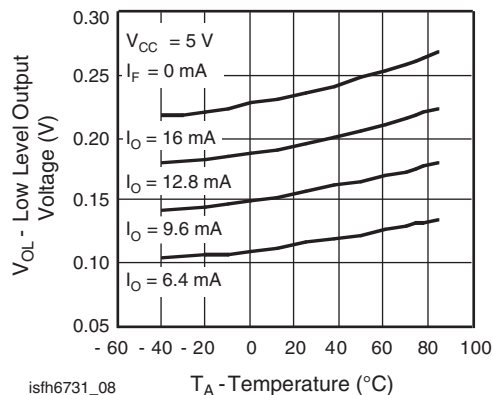


Fig. 8 - Typical Low Level Output Voltage vs. Temperature

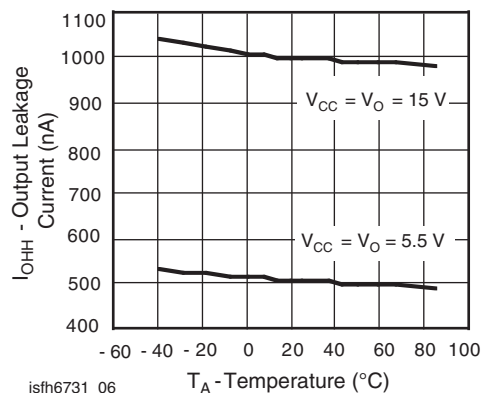


Fig. 6 - Typical Output Leakage Current vs. Temperature

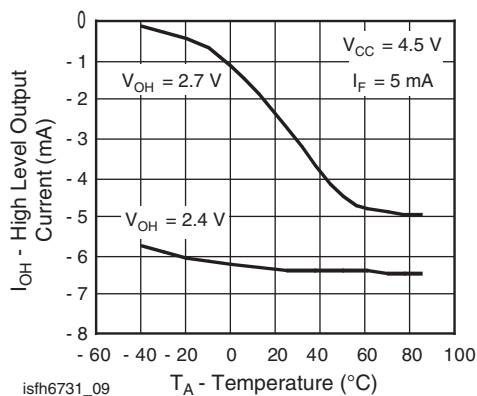


Fig. 9 - Typical High Level Output Current vs. Temperature

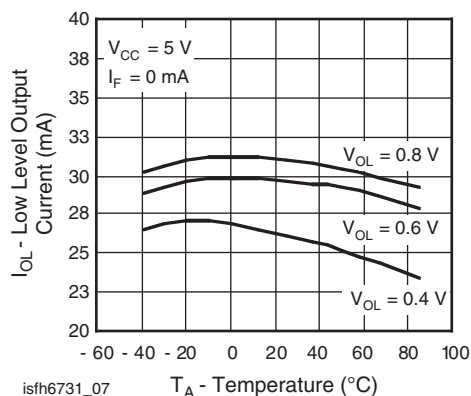


Fig. 7 - Typical Low Level Output Current vs. Temperature

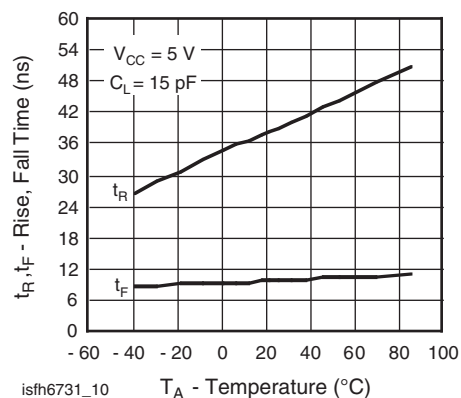


Fig. 10 - Rise and Fall Time vs. Ambient Temperature

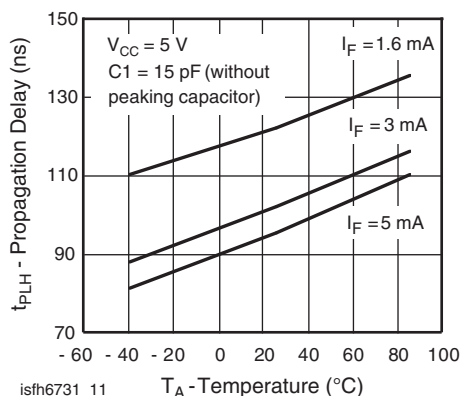


Fig. 11 - Typical Propagation Delays to Logic High vs. Temperature

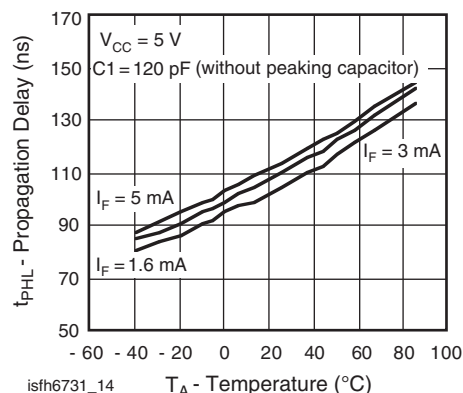


Fig. 14 - Typical Propagation Delays to Logic Low vs. Temperature

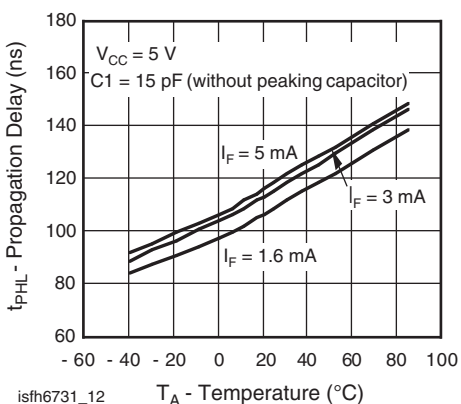


Fig. 12 - Typical Propagation Delays to Logic Low vs. Temperature

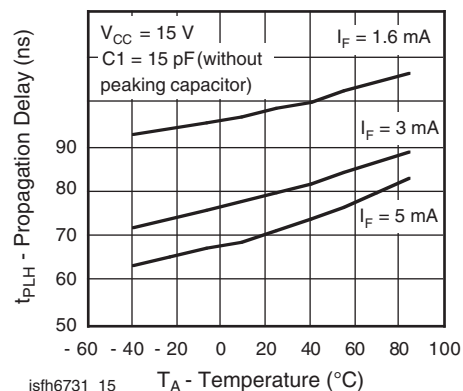


Fig. 15 - Typical Propagation Delays to Logic High vs. Temperature

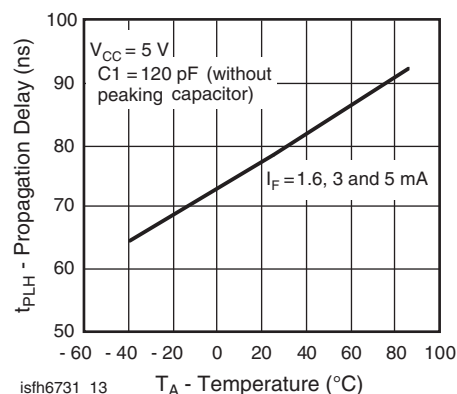


Fig. 13 - Typical Propagation Delays to Logic High vs. Temperature

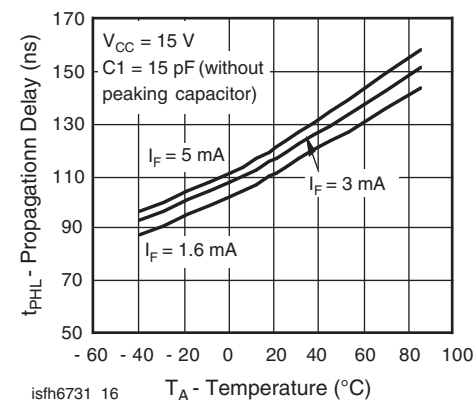


Fig. 16 - Typical Propagation Delays to Logic Low vs. Temperature

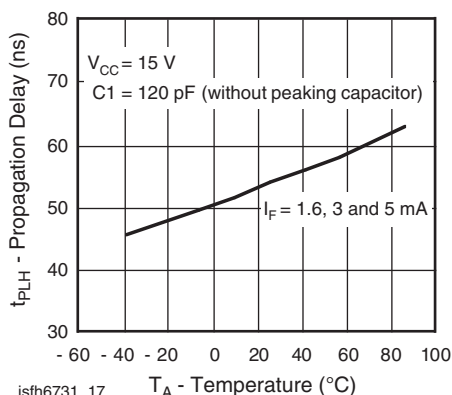


Fig. 17 - Typical Propagation Delays to Logic High vs. Temperature

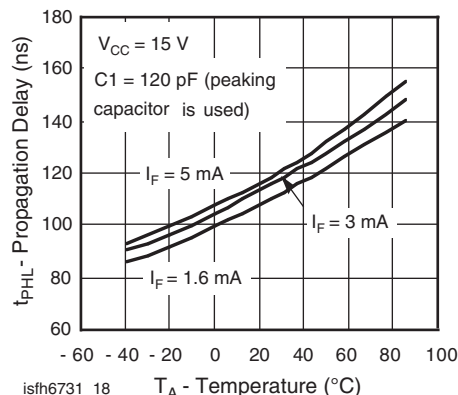


Fig. 18 - Typical Propagation Delays to Logic Low vs. Temperature

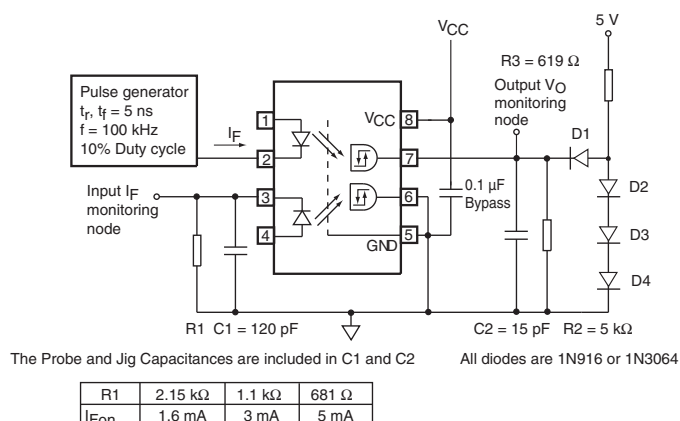
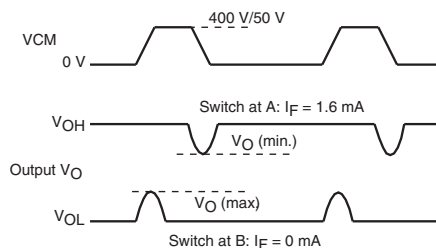
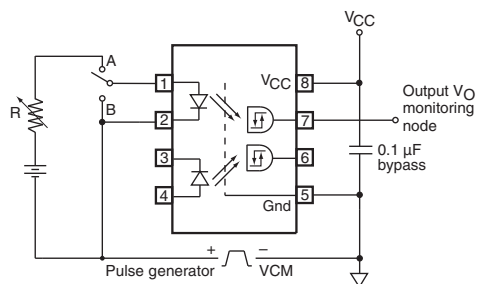

Fig. 19 - Test Circuit for t_{PLH}


Fig. 20 - Test Circuit for Common Mode Transient Immunity and Typical Waveforms



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